



# Taiyo's Photo Imageable Dielectric for High Density Substrate Applications

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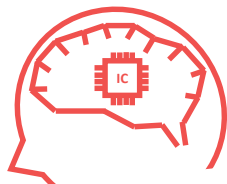
## Agenda

- Motivation for High Density RDL
- Taiyo's Material Portfolio
- Why and What is PID?
- PID Performance
- High Density RDL Demo
- Summary

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## New Applications: Large Data Bandwidth Monsters



AI



Cloud computing



Autonomous car



5G



VR/AR

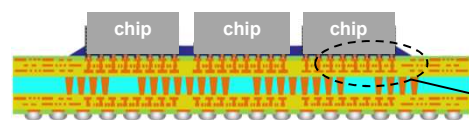
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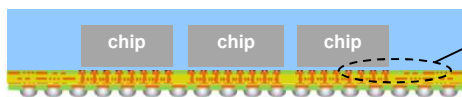
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## Need in High-Density RDL for Advanced IC Packaging

Substrates/Interposers

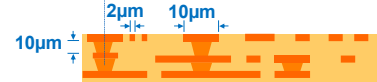


High density Fan-out

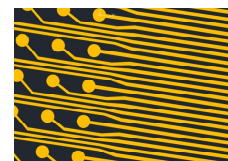


High density RDL

Cross section



Top view



Dielectric material capable of

- 10 µm small micro-via formation
- 2 µm L/S fine Cu wiring patterning

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## Taiyo's Portfolio for IC Packaging Substrate and PCB

**For PCB Solder Resist** Market Share No.1

**PSR-4000 Series**  
**PSR-2000 Series**

**For Substrates & PCB Plugging & Molding**

- THP Series:(Non-solv. Plugging Paste)
- Cellfill Series:(Sheet type Mold)

**For Package Substrates Solder Resist** Market Share No.1

**Liquid type: PSR-4000 AUS series**  
**Dry film type: PSR-800 AUS series**

**For Substrates & PCB Dielectric Materials**

- PVI Series: (Photo imageable for High Density)
- Zaristo Series:(Non-Photo for Low Loss)

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## Why PID (Photo Imageable Dielectric)? – Micro-via Size

Non-photo dielectric + Laser  
→ Technical Limit below 10 μm

Laser Wavelength (nm)	Laser Type	Via Opening Size (μm)
286	Nd-YAG 4th	~50
308	Excimer(XeCl)	~50
355	Nd-YAG 3rd	~70
9400	CO <sub>2</sub>	~80

Technical limit of laser process

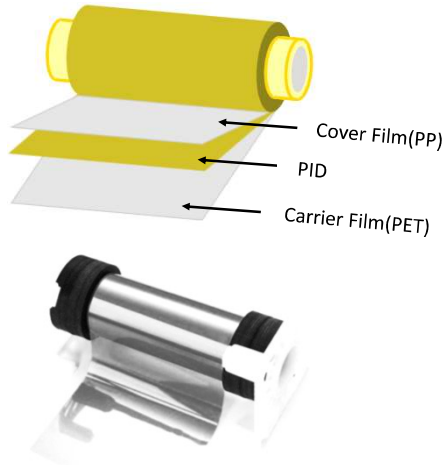
PID can form < 10μm micro-vias

PID can form ultra-small via < 10 μm easily

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### Taiyo's PID: Dry-Film Type



#### Dry Film Benefits

✓ Surface Flatness

- Multi-layer RDL formation
- Fine L/S formation

✓ Large Area Scalable

- Large panel production
- Process uniformity

✓ Low Emission – No solvent drying

- Process reduction
- Environment friendly

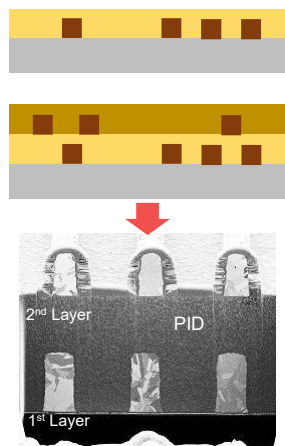
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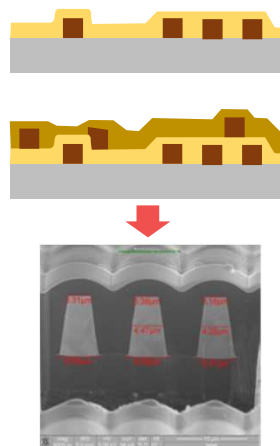
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### Surface Flatness of Dry-Film PID

Dry film Type



Liquid Type



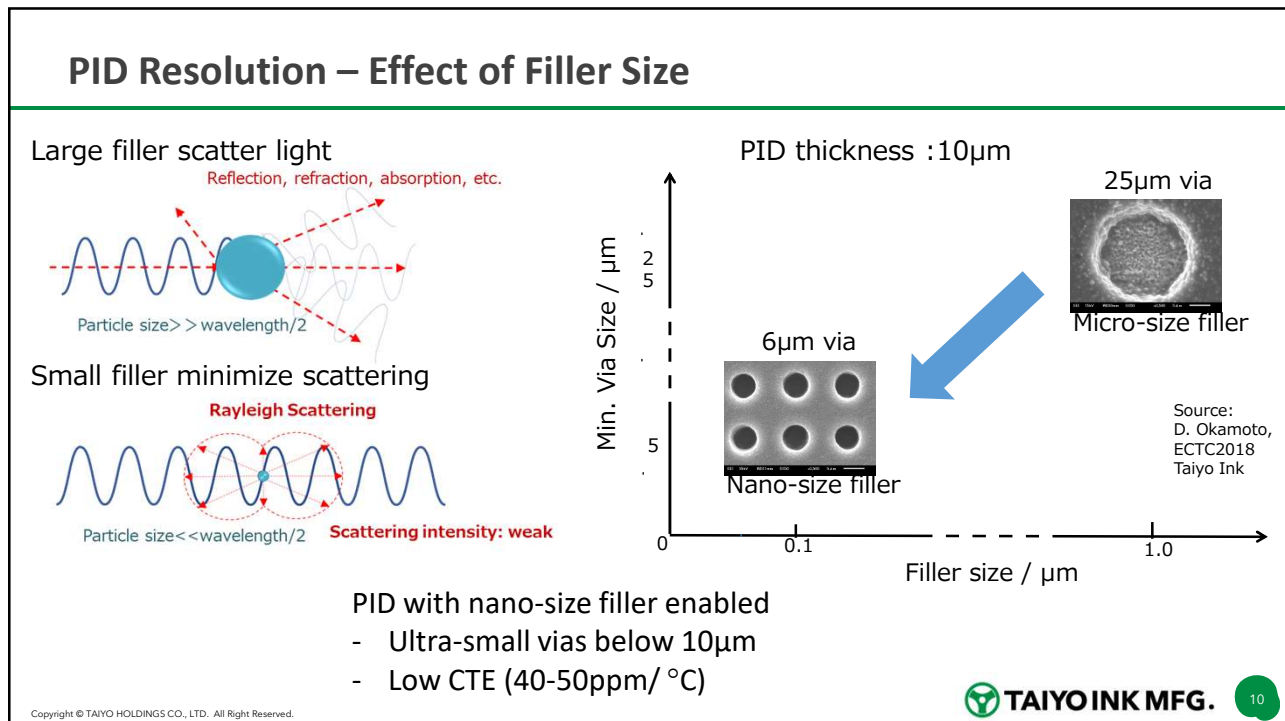
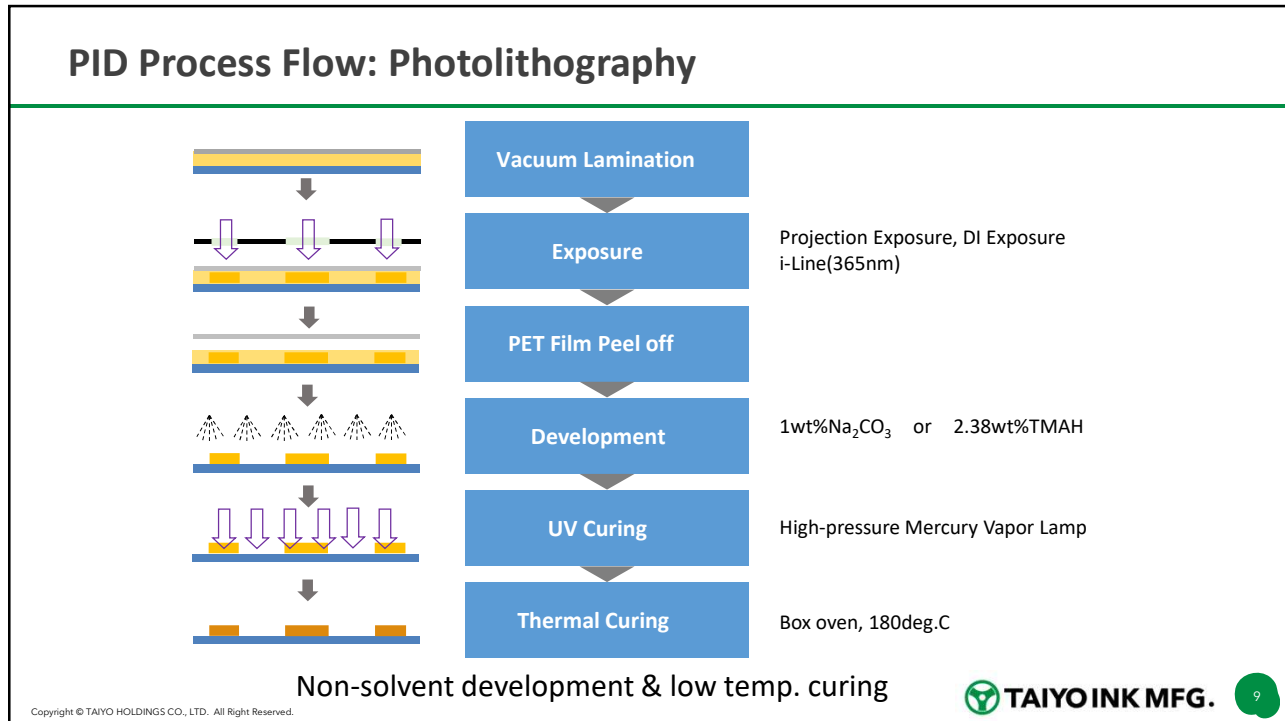
High surface planarity  
→ Beneficial for multi-layer RDL

Source of photo:  
"An introduction for novel multi-layer thin film substrates applied in space transformers"  
C. K. Yang  
SW Test Workshop 2018

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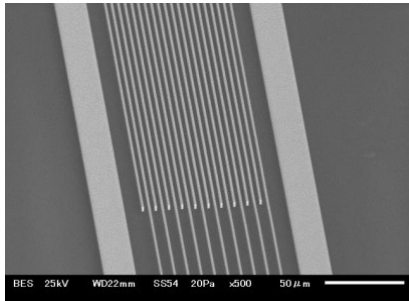


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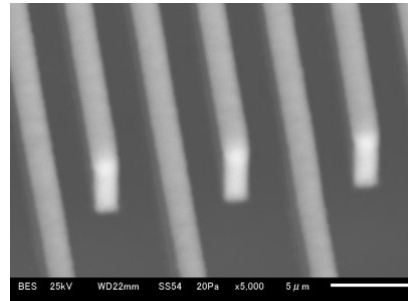


## Semi-Additive Process (SAP) Compatibility

2 $\mu$ m Line/Space Cu Wiring on PID



SEM image (x500)



SEM image (x5000)

Process Steps:

1. PID curing
2. Ti/Cu sputtering
3. Resist patterning
4. Electro Cu plating
5. Resist stripping
6. Seed etching

Courtesy: Mitsui Mining & Smelting Co., Ltd.

Fine RDL formation compatible

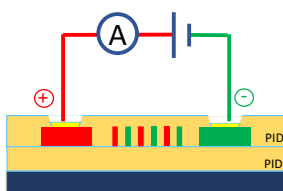
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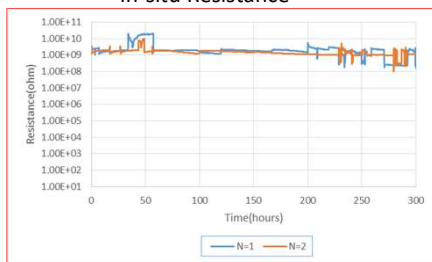
## Insulation Reliability of PID: Biased-HAST (B-HAST) Test

B-HAST configuration

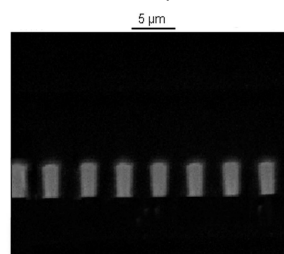


- Preconditioning
- 125deg.C/24h
  - 85deg.C/60%/168h
  - Reflow:260deg.C/3times
- BHAST
- 130deg.C/85%/5V
- (Failure criteria:1.0E+6 ohm)

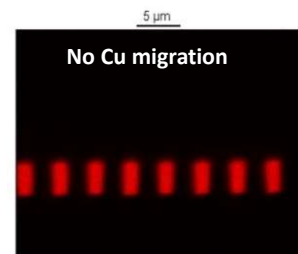
In-situ Resistance



2 $\mu$ m L/S after 300h of B-HAST



SEM image



EDX Cu mapping

High reliability over 300 hours insulation

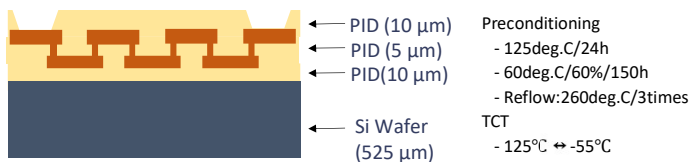
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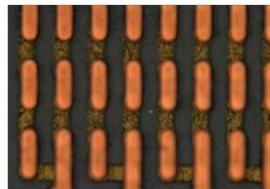
## Mechanical Reliability of PID: TCT Test

TCT configuration

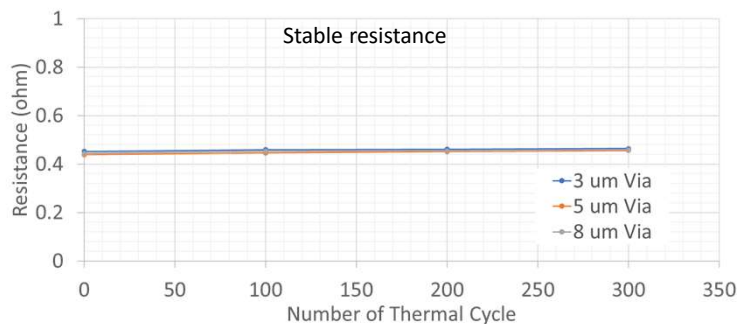
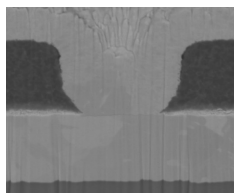


Preconditioning  
 - 125deg.C/24h  
 - 60deg.C/60%/150h  
 - Reflow:260deg.C/3times  
 TCT  
 - 125°C ↔ -55°C

Daisy-chain Top view



3 $\mu\text{m}$  via X-SEM



No failure up to 300 cycles

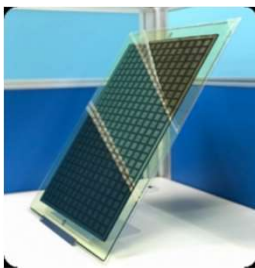
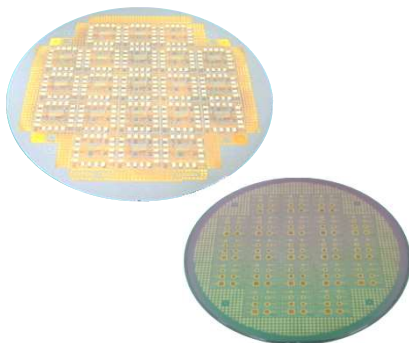


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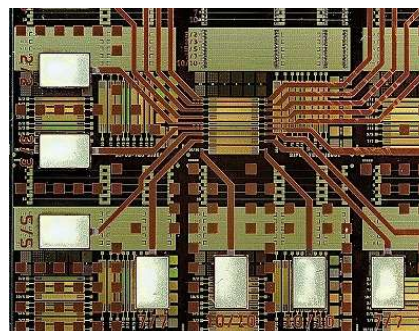
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## Multi-layer RDL with PID on Glass Demo

Glass Test Vehicles Top View



Multi-RDL on Glass



Courtesy: Research Center for Three-Dimensional Semiconductors (Japan), ITRI (Taiwan)

Multi-layer RDL with 2 $\mu\text{m}$  L/S wiring + 10 $\mu\text{m}$  via demonstrated




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### PID Material Properties

Properties	Unit	Taiyo's PID	Ref: standard type Non-photo A	Method
Tg (@TMA)	deg.C	150-155	165-175	Instrument : Q-400 Fulcrum distance 16 mm, t = 30 μm Force : 0.05 N, Mass flow : 100.0 mL -40.00 to 300 deg.C (10 deg.C/min)
CTE alpha 1	ppm	40 – 45	25-30	
Elastic Modulus	GPa	3.5-4.0	6.0-6.5	Instrument : RSA-G2 Temp. : 25 deg.C Constant linear Rate : 2.0e-3 mm/s Duration : 1000 s
Tensile Strength	MPa	100-105	100-110	
Elongation	%	5-7	2-3	
Residual Stress	MPa	20.0-25.0	No data	Instrument : SE700, t = 20 μm
Dk (10 GHz)		3.0-3.1	3.4	SPDR method, t = 30 μm
Df (10 GHz)		0.021-0.023	0.015-0.017	
Water Absorption	%	1.2	1.2	D-1/100, t = 30 μm
Curing Temp.	deg.C	180	190	Box oven

Comparable material properties to standard non-photo dielectric



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### Summary

Taiyo's PID material is beneficial for advanced packaging:

1. High density RDL formation with 2μm L/S & below 10μm micro-via
2. Dry-film type for surface planarity and scalability
3. Excellent material reliability & properties


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